

Maximum Ratings and Thermal Characteristics (TA=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-40	v	
Gate-Source Voltage		V _{GS}	±25	v	
Continuous Drain Current ^(Note 3)	Tc=25°C		-140		
	$T_{C}=100^{\circ}C$	ID	-118	A	
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	-440		
Power Dissipation	Tc=25°C	5	250	W	
	$T_{C}=100^{\circ}C$	Po	125		
Continuous Drain Current ^(Note 4)	T _A =25°C		-20.4		
	T _A =70°C	I _D	-17.1	A	
Power Dissipation	T _A =25°C	D-	3.8	w	
	T _A =70°C	Po	2.6		
Single Pulse Avalanche Current ^(Note 5)		las	-23.5	А	
Single Pulse Avalanche Energy ^(Note 5)		Eas	238	mJ	
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	0.6	°C/W	
	Junction to Ambient	R _{θJA}	40	0/11	



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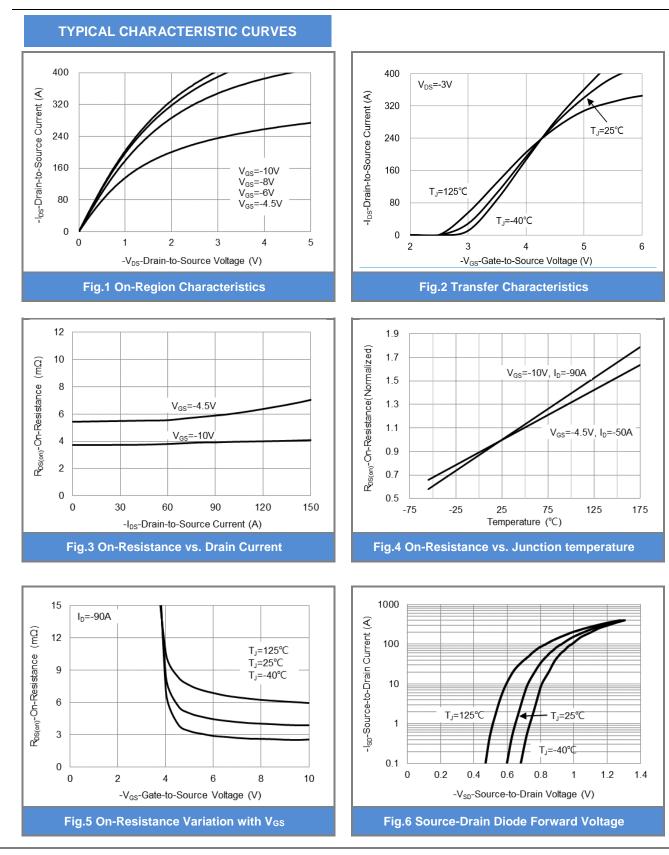
Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		1			•	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-90A	-	4	5	mΩ
		V _{GS} =-4.5V, I _D =-50A	-	5.4	7	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 25V, V_{DS}=0V$	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg	V _{DS} =-32V, I _D =-90A, V _{GS} =-10V	-	142	190	nC
Gate-Source Charge	Qgs		-	24	-	
Gate-Drain Charge	Q _{gd}		-	37	-	
Input Capacitance	Ciss	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	7169	9400	pF
Output Capacitance	Coss		-	695	980	
Reverse Transfer Capacitance	Crss		-	541	760	
Gate resistance	Rg	f=1MHz	-	3.2	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =-32V, I _D =-90A, V _{GS} =-10V, R _G =3Ω	-	15	-	ns
Turn-On Rise Time	tr		-	71	-	
Turn-Off Delay Time	td _(off)		-	114	-	
Turn-Off Fall Time	tf	(1002)	-	92	-	
Drain-Source Diode						
Diode Forward Current	I _S	T 05°0	-	-	-140	A
Pulsed Diode Forward Current	I _{SM}	T _c =25°C	-	-	-440	
Diode Forward Voltage	V _{SD}	I _S =-20A, V _{GS} =0V	-	-0.8	-1.3	V
Reverse Recovery Time	Trr	V _{DD} =-32V,V _{GS} =0V	-	24	-	ns
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	15	-	nC

NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=0.6^{\circ}C/W$, Package limited 140A.
- 4. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=-21.8A, V_{DD}=-30V, V_{GS}=-10V. 100% test at L=0.5mH, I_{AS}=-23.5A in production.
- 6. Guaranteed by design, not subject to production testing.

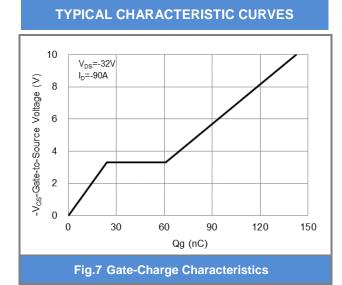
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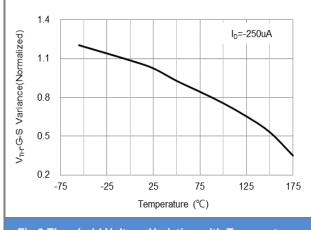


SEMI CONDUCTOR

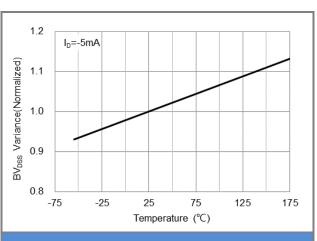
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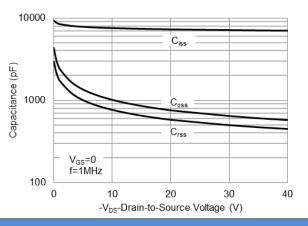




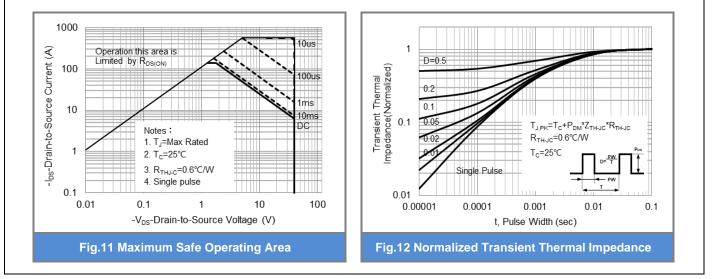














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Product and Packing Information Part No. Package Type **Packing Type** Marking PJB140P04E7-AU TO-263-7L 800 pcs / 13" reel 140P04E **Packaging Information & Mounting Pad Layout** TO-263-7L Dimension TO-263-7L Pad Layout Unit: inch(mm) Unit: inch(mm) 0.413 (10.50) 1.066(1.676) MAX. 0.190(4.825) 15(6.225) 0.420(10.67) 0.065(1.651) 0.045(1.143) 0.416 (10.50) 0.270(6.86) MIN. 0.625(15.88) 0.575(14.605) 0.380(9.65) 0.330(8.38) 0.070(1.78) MAX. 0.01(0.255) MAX. 0.079 (2.00) (6x) 0.036(0.914) 0.020(0.50) 0.015(0.381) 0.110(2.795) 0.070(1.78) 0.010(0.255) UI BSC. 0.05(1.27) BSC. 0.157 0.035 0.05 0.335 (8.52)



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